Computational Modeling on Thermal Control of Electronics using Water-Silicon Carbide Nanofluid

N. K. Kund

Abstract: For the current exploration, CFD codes are developed and executed with water-SiC nanofluid to visualize the thermal concerns of ICs. The convective governing equalities of mass, force and drive are computed for envisaging the thermal issues of ICs. The time pace selected throughout the intact computation is 0.0001 s. The soundings affect CFD forecasts of temperature curve, temperature arena plus fluid-solid boundary temperature of IC. The fluid-solid boundary temperature of IC is viewed as 309 K. This stands far less than the chancy limit of 356 K temperature wished for the objective of outwitting thermal cataclysm of IC. Tritely, the temperature of water-SiC nanofluid stands peak contiguous to the IC locality. Further, the temperature of water-SiC nanofluid gently drops with improvement in aloofness from IC. Afterwards, this becomes surrounding temperature in the distant arena precinct. The analogous tinted temperature curve stands accessible. Besides, the harmonizing graph of temperature against distance from IC stands revealed. Tritely, the development of CFD interpretations stand alongside the experiences of outlooks.

Index Terms: IC, CFD Codes, Thermal Control, Water-SiC Nanofluid.

I. INTRODUCTION

An overview of heat generations in electronic gadgets from interconnects to server farm stand demonstrated in figure 1. Electronics thermal control caught numerous routines for illustration. The standard thermal control arrayed heretofore for instance, atmospheric convection is inappropriate for extreme thermal flux treatments. Still, in the preceding years the strange way of thermal control has compelled the researchers’ everywhere within the domain for the routine of nanofluid cooling. Furthermore, the nanofluid thermal control is candidly spirited as ambient thermal control is poor to deliver the drive. Numerical and experimental reviews on heat spreading over rectangular domain are existent in texts [1-7]. Computational and experimental work with solidification are also presented [8-20].

Regardless of the information that the nanofluid cooling equivocates the issues about the extreme heat battle as to ambient thermal control and hence, the treatment of nanofluid remains the significant drive of the extant exploration. Here, the thermal controls of electronics through water-SiC nanofluid stand explored computationally.

II. DEFINITION OF PHYSICAL CONCERN

Figure 2 unveils the physical topic course purview covering a heat generation from integrated circuit (IC) segment indicating the foot edge. Rest three edges are signposted through ambient situations. Here, the thermal controls of electronics is done through water-SiC nanofluid.

Besides, the thermo-physical and model data of SiC nanoparticles reflected in the existent analysis plus the ambient situation involved in the current course computations, are briefed too in understated Table 1.
Computational Modeling on Thermal Control of Electronics Using Water-Silicon Carbide Nanofluid

### III. NUMERICAL METHODOLOGY

As declared above, the figure 2 reveals the CFD worktable aimed at computing the physical topic course. To facilitate the CFD forecasts the binding stages such as constructing geometry and purview, meshing and initialization are followed to run the simulation. Here, the prevailing equalities (as termed below through equalities 1-4) of mass, force and drive beside the edge states are chosen. Linearized equalities are computed through the CFD codes. After the development of computations, CFD codes form the shapes and curls through that numerous graphs stand strained to amalgam the CFD forecasts through the prognoses. With the later dispensation the forecasts are scrupulously explored aimed at receiving abundant acumens.

#### Continuity:

\[ \frac{\partial u}{\partial x} + \frac{\partial v}{\partial y} = 0 \]  

(1)

#### X-momentum:

\[ \rho \left( \frac{\partial u}{\partial t} + u \frac{\partial u}{\partial x} + v \frac{\partial u}{\partial y} \right) = -\frac{\partial P}{\partial x} + \mu \left( \frac{\partial^2 u}{\partial x^2} + \frac{\partial^2 u}{\partial y^2} \right) \]  

(2)

#### Y-momentum:

\[ \rho \left( \frac{\partial v}{\partial t} + u \frac{\partial v}{\partial x} + v \frac{\partial v}{\partial y} \right) = -\frac{\partial P}{\partial y} + \mu \left( \frac{\partial^2 v}{\partial x^2} + \frac{\partial^2 v}{\partial y^2} \right) \]  

#### Energy:

\[ \left( \frac{\partial T}{\partial t} + u \frac{\partial T}{\partial x} + v \frac{\partial T}{\partial y} \right) = \alpha \left( \frac{\partial^2 T}{\partial x^2} + \frac{\partial^2 T}{\partial y^2} \right) \]  

(4)

In the existent analysis, CFD codes are developed and executed with water-SiC nanofluid to visualize the thermal concerns of ICs. The convective governing equalities of mass, force and drive are computed for envisaging the thermal issues of ICs. The time pace selected throughout the intact computation is 0.0001 s.

#### IV. RESULT AND DISCUSSIONS

CFD codes are developed and executed with water-SiC nanofluid. It envisages the impacts on thermal control of ICs. The soundings affect CFD forecasts of temperature curve, temperature arena plus fluid-solid boundary temperature of IC.

### Impact of Water-SiC Nanofluid on IC Thermal Control

To facilitate the reconnoitering for the stimulus of water-SiC nanofluid on IC cooling, the contemporaneous corporeal archetype stands computed numerically bearing in mind both thermophysical and model data regarding the standing statuses.

**Table 1. Thermophysical and model data.**

<table>
<thead>
<tr>
<th>Nanoparticle Properties</th>
<th>SiC</th>
</tr>
</thead>
<tbody>
<tr>
<td>Density, ( \rho ) (Kg/m(^3))</td>
<td>3162</td>
</tr>
<tr>
<td>Specific heat, ( C_p ) (J/kg.K)</td>
<td>676</td>
</tr>
<tr>
<td>Thermal conductivity, ( k ) (W/m.K)</td>
<td>492</td>
</tr>
</tbody>
</table>

**Model Data**

<table>
<thead>
<tr>
<th>Values</th>
</tr>
</thead>
<tbody>
<tr>
<td>Cavity size</td>
</tr>
<tr>
<td>IC size</td>
</tr>
<tr>
<td>Ambient temperature</td>
</tr>
<tr>
<td>IC heat transfer rate/area</td>
</tr>
</tbody>
</table>

Figure 3 reveals the CFD forecast of temperature arena besides the tinted measuring scale screening the temperature values over K. It stands viewed at the documented archetype statuses bearing in mind the water-SiC nanofluid for IC thermal control. The fluid-solid boundary temperature of IC is viewed as 309 K. This stands far less than the chancy limit of 356 K temperature wished for the objective of outwitting thermal cataclysm of IC.
Truly, the temperature of water-SiC nanofluid stands peak contiguous to the IC locality. Further, the temperature of water-SiC nanofluid gently drops with improvement in aloofness from IC. Afterwards, this becomes surrounding temperature in the distant arena precinct.

The analogous tinted temperature curve stands accessible in figure 4 on top. Besides, the harmonizing graph of temperature against distance from IC stands revealed in figure 5. Truly, the development of CFD elucidations stand along the frameworks of expectancies.

![Temperature curve with water-SiC nanofluid](image)

**Figure 4. Temperature curve with water-SiC nanofluid**

![Temperature vs. distance from IC](image)

**Figure 5. Temperature vs. distance from IC**

**V. CONCLUSION**

In the ongoing analysis, CFD codes are developed and executed with water-SiC nanofluid to visualize the thermal concerns of ICs. The convective governing equalities of mass, force and drive are computed for envisaging the thermal issues of ICs. The time pace selected throughout the intact computation is 0.0001 s. The soundings affect CFD forecasts of temperature curve, temperature arena plus fluid-solid boundary temperature of IC. The fluid-solid boundary temperature of IC is viewed as 309 K. This stands far less than the chancy limit of 356 K temperature wished for the objective of outwitting thermal cataclysm of IC. Truly, the temperature of water-SiC nanofluid stands peak contiguous to the IC locality. Further, the temperature of water-SiC nanofluid gently drops with improvement in aloofness from IC. Afterwards, this becomes surrounding temperature in the distant arena precinct. The analogous tinted temperature curve stands accessible. Besides, the harmonizing graph of temperature against distance from IC stands revealed. Truly, the development of CFD elucidations stand along the backgrounds of expectancies.

**ACKNOWLEDGMENT**

Necessary support from VSSUT Burla, for completing this document is greatly acknowledged. Truthfully, the author is thankful to the reviewers and journal editorial panel for their careful as well as innate reviews to this article.

**REFERENCES**

Computational Modeling on Thermal Control of Electronics Using Water-Silicon Carbide Nanofluid


AUTHORS PROFILE

Dr. N. K. Kund has obtained both M.Tech. & Ph.D. in Mechanical Engineering from Indian Institute of Science Bangalore. He has also obtained B.Tech.(Hons) in Mechanical Engineering from IGIT Sarang, Utkal University Bhubaneswar. He has published several research papers in international journals and also guided many research scholars, besides, wide teaching and research experience. He is presently working as Associate Professor in the Department of Production Engineering, VSSUT Burla (A Government Technical University).